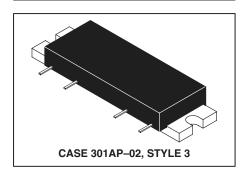
# The RF Line UMTS Band RF Linear LDMOS Amplifier

Designed for Class AB amplifier applications in 50 ohm systems operating in the UMTS frequency band. A silicon FET design provides outstanding linearity and gain. In addition, the excellent group delay and phase linearity characteristics are ideal for digital modulation systems.

- Typical W–CDMA Performance for  $V_{DD}=28$  Volts,  $V_{bias}=8$  Volts,  $I_{DQ}=550$  mA, Channel Bandwidth = 3.84 MHz, Adjacent Channels at  $\pm$  5 MHz, ACPR Measured in 3.84 MHz Bandwidth. Peak/Avg. = 8.5 dB @ 0.01% Probability on CCDF, 3GPP Test Model 1, 64 DTCH.
- Adjacent Channel Power: -50 dBc @ 30 dBm, 5 MHz Channel Spacing
- Power Gain: 23.7 dB Min (@ f = 2140 MHz)
- Excellent Phase Linearity and Group Delay Characteristics
- 0.2 dB Typical Gain Flatness
- Ideal for Feedforward Base Station Applications

## **MHPA21010**

2110–2170 MHz 10 W, 23.7 dB RF HIGH POWER LDMOS AMPLIFIER



#### MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
DC Supply Voltage	$V_{DD}$	30	Vdc
RF Input Power (Single Carrier CW)	P <sub>in</sub>	+20	dBm
Storage Temperature Range	T <sub>stg</sub>	-40 to +100	°C
Operating Case Temperature Range	T <sub>C</sub>	-20 to +100	°C
Quiescent Bias Current	$I_{DQ}$	750	mA

### **ELECTRICAL CHARACTERISTICS** (V<sub>DD</sub> = 28 Vdc, V<sub>BIAS</sub> $\cong$ 8 V Set for Supply Current of 550 mA, T<sub>C</sub> = 25°C, 50 $\Omega$ System)

Characteristic		Symbol	Min	Тур	Max	Unit
Supply Current		I <sub>DD</sub>	_	550	_	mA
Power Gain	(f = 2140 MHz)	Gp	23.7	25	_	dB
Gain Flatness	(f = 2110-2170 MHz)	G <sub>F</sub>	_	0.2	0.6	dB
Power Output @ 1 dB Comp.	(f = 2140 MHz)	P1dB	_	41.5	_	dBm
Input VSWR	(f = 2110-2170 MHz)	VSWR <sub>in</sub>	_	1.5:1	2:1	
Noise Figure	(f = 2140 MHz)	NF	_	_	10	dB
Adjacent Channel Power Rejection @ 30 5 MHz Channel Spacing	dBm Avg., 3.84 MHz BW,	ACPR	_	<b>-</b> 55	-50	dBc



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### TYPICAL CHARACTERISTICS

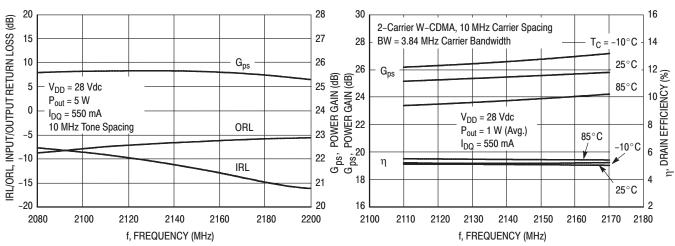


Figure 1. Two-Tone Power Gain, Input Return Loss and Output Return Loss versus Frequency

Figure 2. 2-Carrier W-CDMA Power Gain and Efficiency versus Frequency

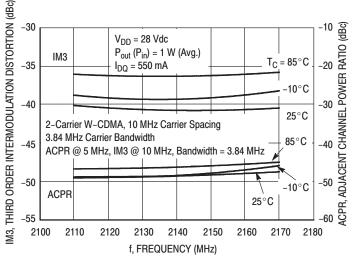


Figure 3. 2-Carrier W-CDMA IM3 and ACPR versus Frequency

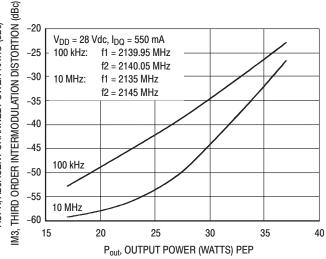


Figure 4. Two-Tone W-CDMA IM3 versus **Output Power** 

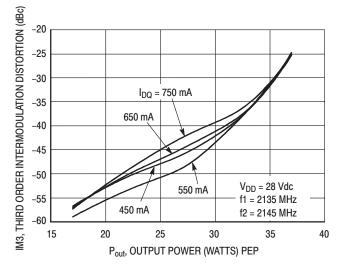


Figure 5. Third Order Intermodulation Distortion versus Output Power

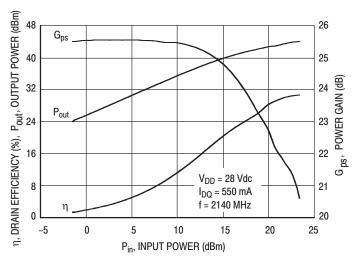


Figure 6. CW Output Power, Efficiency and Gain versus Input Power

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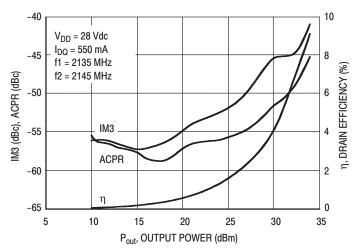
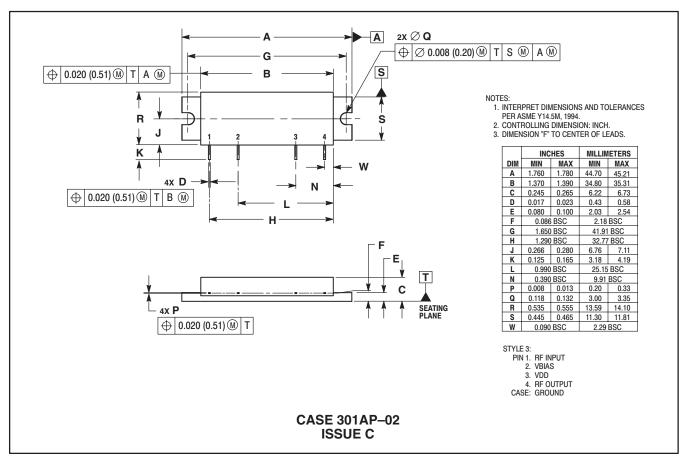


Figure 7. 2-Carrier W-CDMA ACPR, IM3 and Efficiency versus Output Power

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### PACKAGE DIMENSIONS



NOTE: V<sub>DD</sub> (Pin 3) should always be applied before V<sub>BIAS</sub> (Pin 2).

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